

## TLV237x 500- $\mu$ A/Ch, 3-MHz Rail-to-Rail Input and Output Operational Amplifiers With Shutdown

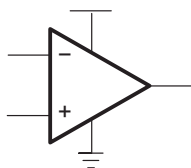
### 1 Features

- Rail-to-Rail Input and Output
- Wide Bandwidth: 3 MHz
- High Slew Rate: 2.4 V/ $\mu$ s
- Supply Voltage Range: 2.7 V to 16 V
- Supply Current: 550  $\mu$ A/Channel
- Low-Power Shutdown Mode
  - $I_{DD(SHDN)}$ : 25  $\mu$ A/Channel
- Input Noise Voltage: 39 nV/ $\sqrt{\text{Hz}}$
- Input Bias Current: 1 pA
- Specified Temperature Range:
  - $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$  (Industrial Grade)
- Ultra-Small Packaging:
  - 5- or 6-Pin SOT-23 (TLV2370, TLV2371)
  - 8- or 10-Pin MSOP (TLV2372, TLV2373)

### 2 Applications

- White Goods
- Handheld Test Equipment
- Portable Blood Glucose Systems
- Remote Sensing
- Active Filters
- Industrial Automation
- Battery-Powered Electronics

**Operational Amplifier**



### 3 Description

The TLV237x single-supply operational amplifiers provide rail-to-rail input and output capability. The TLV237x takes the minimum operating supply voltage down to 2.7 V over the extended industrial temperature range while adding the rail-to-rail output swing feature. The TLV237x also provides 3-MHz bandwidth from only 550  $\mu$ A. The maximum recommended supply voltage is 16 V, which allows the devices to be operated from ( $\pm 8$ -V supplies down to  $\pm 1.35$  V) a variety of rechargeable cells.

The CMOS inputs enable use in high-impedance sensor interfaces, with the lower voltage operation making an ideal alternative for the TLC227x in battery-powered applications. The rail-to-rail input stage further increases its versatility. The TLV237x is the seventh member of a rapidly growing number of RRIO products available from TI, and it is the first to allow operation up to 16-V rails with good ac performance.

All members are available in PDIP and SOIC with the singles in the small SOT-23 package, duals in the MSOP, and quads in the TSSOP package.

The 2.7-V operation makes the TLV237x compatible with Li-Ion powered systems and the operating supply voltage range of many micro-power microcontrollers available today including TI's MSP430.

**Device Information<sup>(1)</sup>**

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TLV237x	PDIP (8)	9.81 mm x 6.35 mm
	PDIP (14)	19.30 mm x 6.35 mm
	SOIC (8)	4.90 mm x 3.91 mm
	SOIC (14)	8.65 mm x 3.91 mm
	TSSOP (14)	5.00 mm x 4.40 mm
	TSSOP (16)	
	SOT-23 (6)	2.90 mm x 1.60 mm
	SOT-23 (5)	
	VSSOP (8)	3.00 mm x 3.00 mm
	VSSOP (10)	

(1) For all available packages, see the orderable addendum at the end of the data sheet.



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## 4 Revision History

Changes from Revision E (May 2016) to Revision F	Page
• Changed names of pins 2 and 3 in TLV2372 D, DGK, and P packages pinout diagram .....	<b>4</b>

Changes from Revision D (January 2005) to Revision E	Page
• Added <i>ESD Ratings</i> table, <i>Feature Description</i> section, <i>Device Functional Modes</i> , <i>Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section. ....	<b>1</b>
• Deleted <i>TLV2370 and TLV2371 Available Options</i> , <i>TLV2372 AND TLV2373 Available Options</i> , and <i>TLV2374 and TLV2375 Available Options</i> tables .....	<b>3</b>
• Deleted <i>Continuous total power dissipation</i> and <i>lead temperature</i> specifications from <i>Absolute Maximum Ratings</i> table ...	<b>8</b>
• Deleted <i>Dissipation Ratings</i> table .....	<b>14</b>

## 5 Device Comparison Tables

Table 1. Selection of Signal Amplifier Products<sup>(1)</sup>

DEVICE	V <sub>DD</sub> (V)	V <sub>IO</sub> (μV)	I <sub>Q</sub> /Ch (μA)	I <sub>IB</sub> (pA)	GBW (MHz)	SR (V/μs)	SHUTDOWN	RAIL-TO-RAIL	SINGLES, DUALS, QUADS
TLV237x	2.7 to 16	500	550	1	3	2.4	Yes	I/O	S, D, Q
TLC227x	4 to 16	300	1100	1	2.2	3.6	—	O	D, Q
TLV27x	2.7 to 16	500	550	1	3	2.4	—	O	S, D, Q
TLC27x	3 to 16	1100	675	1	1.7	3.6	—	—	S, D, Q
TLV246x	2.7 to 16	150	550	1300	6.4	1.6	Yes	I/O	S, D, Q
TLV247x	2.7 to 16	250	600	2	2.8	1.5	Yes	I/O	S, D, Q
TLV244x	2.7 to 10	300	725	1	1.8	1.4	—	O	D, Q

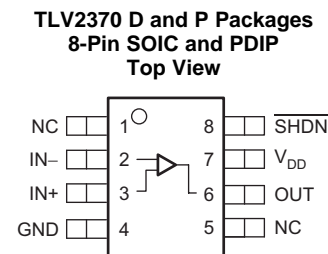
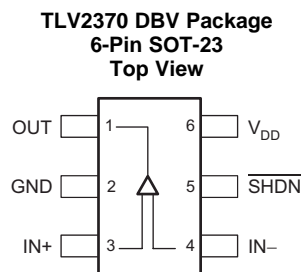
(1) Typical values measured at 5 V and 25°C.

Table 2. Family Package Table<sup>(1)</sup>

DEVICE	NUMBER OF CHANNELS	PACKAGE TYPES					SHUTDOWN	UNIVERSAL EVM BOARD
		PDIP	SOIC	SOT-23	TSSOP	MSOP		
TLV2370	1	8	8	6	—	—	Yes	See the <i>EVM Selection Guide</i>
TLV2371	1	8	8	5	—	—	—	
TLV2372	2	8	8	—	—	8	—	
TLV2373	2	14	14	—	—	10	Yes	
TLV2374	4	14	14	—	14	—	—	
TLV2375	4	16	16	—	16	—	Yes	

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at [www.ti.com](http://www.ti.com).

## 6 Pin Configuration and Functions



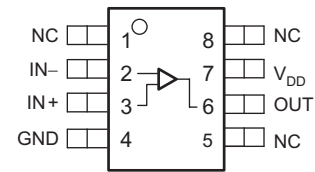
Pin Functions: TLV2370

NAME	PIN		I/O	DESCRIPTION
	SOT-23	SOIC, PDIP		
GND	2	4	—	Ground connection
IN-	4	2	I	Negative (inverting) input
IN+	3	3	I	Positive (noninverting) input
NC	—	1, 5	—	No internal connection (can be left floating)
OUT	1	6	O	Output
SHDN	5	8	I	Shutdown control (active low, can be left floating)
V <sub>DD</sub>	6	7	—	Positive power supply

**TLV2371 DBV Package  
 5-Pin SOT-23  
 Top View**



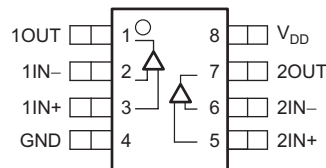
**TLV2371 D and P Packages  
 8-Pin SOIC and PDIP  
 Top View**



**Pin Functions: TLV2371**

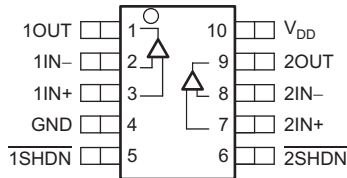
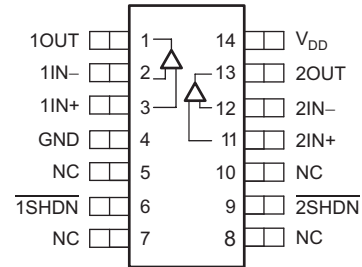
NAME	PIN		I/O	DESCRIPTION
	SOT-23	SOIC, PDIP		
GND	2	4	—	Ground connection
IN-	4	2	I	Negative (inverting) input
IN+	3	3	I	Positive (noninverting) input
NC	—	1, 5, 8	—	No internal connection (can be left floating)
OUT	1	6	O	Output
V <sub>DD</sub>	5	7	—	Positive power supply

**TLV2372 D, DGK, and P Packages  
 8-Pin SOIC, VSSOP, and PDIP  
 Top View**



**Pin Functions: TLV2372**

NAME	PIN		I/O	DESCRIPTION
	SOIC, VSSOP, PDIP			
GND	4		—	Ground connection
1IN-	2		I	Inverting input, channel 1
1IN+	3		I	Noninverting input, channel 1
2IN-	6		I	Inverting input, channel 2
2IN+	5		I	Noninverting input, channel 2
1OUT	1		O	Output, channel 1
2OUT	7		O	Output, channel 2
V <sub>DD</sub>	8		—	Positive power supply

**TLV2373 DGS Package  
10-Pin VSSOP  
Top View**

**TLV2373 D and N Packages  
14-Pin SOIC and PDIP  
Top View**

**Pin Functions: TLV2373**

NAME	PIN		I/O	DESCRIPTION
	SOIC, PDIP	VSSOP		
GND	4	4	—	Ground connection
1IN-	2	2	I	Inverting input, channel 1
1IN+	3	3	I	Noninverting input, channel 1
2IN-	12	8	I	Inverting input, channel 2
2IN+	11	7	I	Noninverting input, channel 2
1OUT	1	1	O	Output, channel 1
2OUT	13	9	O	Output, channel 2
1SHDN	6	5	I	Shutdown control, channel 1, (active low, can be left floating)
2SHDN	9	6	I	Shutdown control, channel 2, (active low, can be left floating)
V <sub>DD</sub>	14	10	—	Positive power supply
NC	5, 7, 8, 10	—	—	No internal connection (can be left floating)

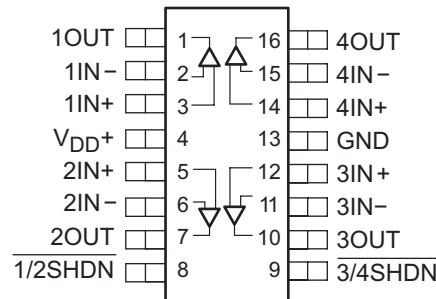
TLV2374 D, N, and PW Packages  
 14-Pin SOIC, PDIP, and TSSOP  
 Top View



Pin Functions: TLV2374

PIN		I/O	DESCRIPTION
NAME	SOIC, PDIP, TSSOP		
GND	11	—	Ground connection
1IN-	2	I	Inverting input, channel 1
1IN+	3	I	Noninverting input, channel 1
2IN-	6	I	Inverting input, channel 2
2IN+	5	I	Noninverting input, channel 2
3IN-	9	I	Inverting input, channel 3
3IN+	10	I	Noninverting input, channel 3
4IN-	13	I	Inverting input, channel 4
4IN+	12	I	Noninverting input, channel 4
1OUT	1	O	Output, channel 1
2OUT	7	O	Output, channel 2
3OUT	8	O	Output, channel 3
4OUT	14	O	Output, channel 4
V <sub>DD</sub>	4	—	Positive power supply

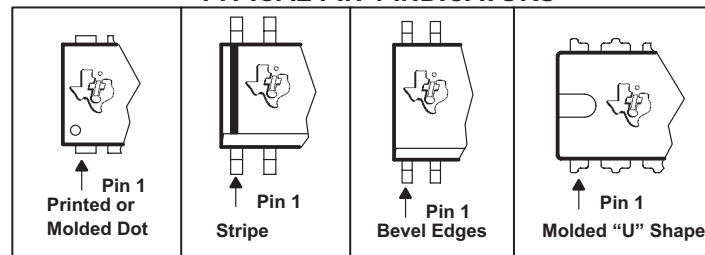
TLV2375 D, N, and PW Packages  
16-Pin SOIC, PDIP, and TSSOP  
Top View



Pin Functions: TLV2375

PIN		I/O	DESCRIPTION
NAME	SOIC, PDIP, TSSOP		
GND	13	—	Ground connection
1IN-	2	I	Inverting input, channel 1
2IN-	6	I	Inverting input, channel 2
3IN-	11	I	Inverting input, channel 3
4IN-	15	I	Inverting input, channel 4
1IN+	3	I	Noninverting input, channel 1
2IN+	5	I	Noninverting input, channel 2
3IN+	12	I	Noninverting input, channel 3
4IN+	14	I	Noninverting input, channel 4
1OUT	1	O	Output, channel 1
2OUT	7	O	Output, channel 2
3OUT	10	O	Output, channel 3
4OUT	16	O	Output, channel 4
1/2SHDN	8	I	Shutdown control, channels 1 and 2, (active low, can be left floating)
3/4SHDN	9	I	Shutdown control, channels 3 and 4, (active low, can be left floating)
V <sub>DD</sub>	4	—	Positive power supply

TYPICAL PIN 1 INDICATORS



If there is not a Pin 1 indicator, turn device to enable reading the symbol from the left to right. Pin 1 is at the lower left corner of the device.

Figure 1. Typical Pin 1 Indicators

## 7 Specifications

### 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
Voltage	Supply voltage, $V_{DD}$ <sup>(2)</sup>		16.5	V
	Differential input voltage, $V_{ID}$	$-V_{DD}$	$V_{DD}$	
	Input voltage, $V_I$ <sup>(2)</sup>	-0.2	$V_{DD} + 0.2$	
Current	Input current, $I_{IN}$	-10	10	mA
	Output current, $I_O$	-100	100	
Temperature	Operating free-air temperature, $T_A$ : I-suffix	-40	125	°C
	Maximum junction temperature, $T_J$		150	
	Storage temperature, $T_{stg}$	-65	150	

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential voltages, are with respect to GND.

### 7.2 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted).

		MIN	MAX	UNIT
Supply voltage, $V_{DD}$	Single supply	2.7	16	V
	Split supply	$\pm 1.35$	$\pm 8$	
Common-mode input voltage, $V_{CM}$		0	$V_{DD}$	V
Operating free-air temperature, $T_A$	I-suffix	-40	125	°C
Turnon voltage (shutdown pin voltage level), $V_{(ON)}$ , relative to GND pin voltage			2	V
Turnoff (shutdown pin voltage level), $V_{(OFF)}$ , relative to GND pin voltage		0.8		V



### 7.3 Thermal Information: TLV2370

THERMAL METRIC <sup>(1)</sup>		TLV2370			UNIT
		DBV (SOT-23)	D (SOIC)	P (PDIP)	
		6 PINS	8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	228.5	138.4	49.2	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	99.1	89.5	39.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	54.6	78.6	26.4	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	7.7	29.9	15.4	°C/W
$\Psi_{JB}$	Junction-to-board characterization parameter	53.8	78.1	26.3	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

### 7.4 Thermal Information: TLV2371

THERMAL METRIC <sup>(1)</sup>		TLV2371			UNIT
		DBV (SOT-23)	D (SOIC)	P (PDIP)	
		5 PINS	8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	228.5	138.4	49.2	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	99.1	89.5	39.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	54.6	78.6	26.4	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	7.7	29.9	15.4	°C/W
$\Psi_{JB}$	Junction-to-board characterization parameter	53.8	78.1	26.3	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

### 7.5 Thermal Information: TLV2372

THERMAL METRIC <sup>(1)</sup>		TLV2372			UNIT
		D (SOIC)	DGK (VSSOP)	P (PDIP)	
		8 PINS	8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	138.4	191.2	49.2	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	89.5	61.9	39.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	78.6	111.9	26.4	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	29.9	5.1	15.4	°C/W
$\Psi_{JB}$	Junction-to-board characterization parameter	78.1	110.2	26.3	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 7.6 Thermal Information: TLV2373

THERMAL METRIC <sup>(1)</sup>		TLV2373			UNIT
		DGS (VSSOP)	D (SOIC)	P (PDIP)	
		10 PINS	14 PINS	14 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	166.5	67	66.3	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	41.8	24.1	20.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	86.1	22.5	26.8	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	1.5	2.2	2.1	°C/W
$\Psi_{JB}$	Junction-to-board characterization parameter	84.7	22.1	26.2	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 7.7 Thermal Information: TLV2374

THERMAL METRIC <sup>(1)</sup>		TLV2374			UNIT
		D (SOIC)	N (PDIP)	PW (TSSOP)	
		14 PINS	14 PINS	14 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	67	66.3	121	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	24.1	20.5	49.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	22.5	26.8	62.8	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	2.2	2.1	5.9	°C/W
$\Psi_{JB}$	Junction-to-board characterization parameter	22.1	26.2	62.2	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 7.8 Thermal Information: TLV2375

THERMAL METRIC <sup>(1)</sup>		TLV2375			UNIT
		D (SOIC)	N (PDIP)	PW (TSSOP)	
		16 PINS	16 PINS	16 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	83	55.8	115.6	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	44	43.1	50.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	40.5	35.8	60.7	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	11.5	27.9	7.4	°C/W
$\Psi_{JB}$	Junction-to-board characterization parameter	40.2	35.7	60.1	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 7.9 Electrical Characteristics

at  $T_A = 25^\circ\text{C}$ ,  $V_{DD} = 2.7\text{ V}$ ,  $5\text{ V}$ , and  $15\text{ V}$  (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>DC PERFORMANCE</b>						
$V_{OS}$	Input offset voltage	At $T_A = 25^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $V_O = V_{DD}/2$ , $R_S = 50\ \Omega$		2	4.5	mV
		At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $V_O = V_{DD}/2$ , $R_S = 50\ \Omega$			6	mV
$dV_{OS}/dT$	Offset voltage drift	At $T_A = 25^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $V_O = V_{DD}/2$ , $R_S = 50\ \Omega$		2		$\mu\text{V}/^\circ\text{C}$
CMRR	Common-mode rejection ratio	$V_{DD} = 2.7\text{ V}$ , $R_S = 50\ \Omega$	$V_{IC} = 0$ to $V_{DD}$	50	68	dB
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ , $V_{IC} = 0$ to $V_{DD}$	49		
			$V_{IC} = 0$ to $V_{DD} - 1.35\text{ V}$	56	70	
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ , $V_{IC} = 0$ to $V_{DD} - 1.35\text{ V}$	54		
		$V_{DD} = 5\text{ V}$ , $R_S = 50\ \Omega$	$V_{IC} = 0$ to $V_{DD}$	55	72	
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ , $V_{IC} = 0$ to $V_{DD}$	54		
			$V_{IC} = 0$ to $V_{DD} - 1.35\text{ V}$	67	80	
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ , $V_{IC} = 0$ to $V_{DD} - 1.35\text{ V}$	64		
		$V_{DD} = 15\text{ V}$ , $R_S = 50\ \Omega$	$V_{IC} = 0$ to $V_{DD}$	64	82	
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ , $V_{IC} = 0$ to $V_{DD}$	63		
			$V_{IC} = 0$ to $V_{DD} - 1.35\text{ V}$	67	84	
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ , $V_{IC} = 0$ to $V_{DD} - 1.35\text{ V}$	66		
$A_{VD}$	Large-signal differential voltage amplification	$V_{DD} = 2.7\text{ V}$ , $V_{O(PP)} = V_{DD}/2$ , $R_L = 10\text{ k}\Omega$		98	106	dB
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	76		
		$V_{DD} = 5\text{ V}$ , $V_{O(PP)} = V_{DD}/2$ , $R_L = 10\text{ k}\Omega$		100	110	
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	86		
		$V_{DD} = 15\text{ V}$ , $V_{O(PP)} = V_{DD}/2$ , $R_L = 10\text{ k}\Omega$		81	83	
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	79		
<b>INPUT CHARACTERISTICS</b>						
$I_{OS}$	Input offset current	$V_{DD} = 15\text{ V}$ , $V_{IC} = V_O = V_{DD}/2$		1	60	pA
			At $T_A = 70^\circ\text{C}$		100	
			At $T_A = 125^\circ\text{C}$		1000	
$I_B$	Input bias current	$V_{DD} = 15\text{ V}$ , $V_{IC} = V_O = V_{DD}/2$		1	60	pA
			At $T_A = 70^\circ\text{C}$		100	
			At $T_A = 125^\circ\text{C}$		1000	
	Differential input resistance			1000		G $\Omega$
	Common-mode input capacitance	$f = 21\text{ kHz}$		8		pF

### Electrical Characteristics (continued)

at  $T_A = 25^\circ\text{C}$ ,  $V_{DD} = 2.7\text{ V}$ ,  $5\text{ V}$ , and  $15\text{ V}$  (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>OUTPUT CHARACTERISTICS</b>						
$V_{OH}$	High-level output voltage	$V_{DD} = 2.7\text{ V}$	At $T_A = 25^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OH} = -1\text{ mA}$	2.55	2.58	V
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OH} = -1\text{ mA}$	2.48		
		$V_{DD} = 5\text{ V}$	At $T_A = 25^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OH} = -1\text{ mA}$	4.9	4.93	
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OH} = -1\text{ mA}$	4.85		
		$V_{DD} = 15\text{ V}$	At $T_A = 25^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OH} = -1\text{ mA}$	14.92	14.96	
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OH} = -1\text{ mA}$	14.9		
	Low-level output voltage	$V_{DD} = 2.7\text{ V}$	At $T_A = 25^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OH} = -5\text{ mA}$	1.9	2	
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OH} = -5\text{ mA}$	1.6		
		$V_{DD} = 5\text{ V}$	At $T_A = 25^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OH} = -5\text{ mA}$	4.6	4.68	
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OH} = -5\text{ mA}$	4.5		
		$V_{DD} = 15\text{ V}$	At $T_A = 25^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OH} = -5\text{ mA}$	14.7	14.8	
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OH} = -5\text{ mA}$	14.6		
$V_{OL}$	Low-level output voltage	$V_{DD} = 2.7\text{ V}$	At $T_A = 25^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OL} = 1\text{ mA}$		0.1	0.15
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OL} = 1\text{ mA}$			0.22
		$V_{DD} = 5\text{ V}$	At $T_A = 25^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OL} = 1\text{ mA}$		0.05	0.1
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OL} = 1\text{ mA}$			0.15
		$V_{DD} = 15\text{ V}$	At $T_A = 25^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OL} = 1\text{ mA}$		0.05	0.08
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OL} = 1\text{ mA}$			0.1
	Output current	$V_{DD} = 2.7\text{ V}$	At $T_A = 25^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OL} = 5\text{ mA}$		0.52	0.7
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OL} = 5\text{ mA}$			1.1
		$V_{DD} = 5\text{ V}$	At $T_A = 25^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OL} = 5\text{ mA}$		0.28	0.4
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OL} = 5\text{ mA}$			0.5
		$V_{DD} = 15\text{ V}$	At $T_A = 25^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OL} = 5\text{ mA}$		0.19	0.3
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ , $V_{IC} = V_{DD}/2$ , $I_{OL} = 5\text{ mA}$			0.35
$I_O$	Output current	$V_{DD} = 2.7\text{ V}$ , $V_O = 0.5\text{ V}$ from rail	Positive rail		4	
			Negative rail		5	
	$V_{DD} = 5\text{ V}$ , $V_O = 0.5\text{ V}$ from rail	Positive rail		7		
		Negative rail		8		
	$V_{DD} = 15\text{ V}$ , $V_O = 0.5\text{ V}$ from rail	Positive rail		16		
		Negative rail		15		

## Electrical Characteristics (continued)

 at  $T_A = 25^\circ\text{C}$ ,  $V_{DD} = 2.7\text{ V}$ ,  $5\text{ V}$ , and  $15\text{ V}$  (unless otherwise noted).

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT	
<b>POWER SUPPLY</b>								
$I_{DD}$	Supply current (per channel)	$V_{DD} = 2.7\text{ V}$ , $V_O = V_{DD}/2$			470	560	$\mu\text{A}$	
		$V_{DD} = 5\text{ V}$ , $V_O = V_{DD}/2$			550	660		
		$V_{DD} = 15\text{ V}$ , $V_O = V_{DD}/2$	At $T_A = 25^\circ\text{C}$			750		900
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$					1200
PSRR	Power-supply rejection ratio ( $\Delta V_{DD}/\Delta V_{IO}$ )	$V_{DD} = 2.7\text{ V}$ to $15\text{ V}$ , $V_{IC} = V_{DD}/2$ , no load	At $T_A = 25^\circ\text{C}$		70	80	dB	
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$		65			
<b>DYNAMIC PERFORMANCE</b>								
UGBW	Unity gain bandwidth	$V_{DD} = 2.7\text{ V}$	$R_L = 2\text{ k}\Omega$ , $C_L = 10\text{ pF}$			2.4	MHz	
		$V_{DD} = 5\text{ V}$ to $15\text{ V}$	$R_L = 2\text{ k}\Omega$ , $C_L = 10\text{ pF}$			3		
SR	Slew rate at unity gain	$V_{DD} = 2.7\text{ V}$	At $T_A = 25^\circ\text{C}$ , $V_{O(PP)} = V_{DD}/2$ , $C_L = 50\text{ pF}$ , $R_L = 10\text{ k}\Omega$		1.4	2	$\text{V}/\mu\text{s}$	
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ , $V_{O(PP)} =$ $V_{DD}/2$ , $C_L = 50\text{ pF}$ , $R_L = 10\text{ k}\Omega$		1			
		$V_{DD} = 5\text{ V}$	At $T_A = 25^\circ\text{C}$ , $V_{O(PP)} = V_{DD}/2$ , $C_L = 50\text{ pF}$ , $R_L = 10\text{ k}\Omega$		1.6	2.4		
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ , $V_{O(PP)} =$ $V_{DD}/2$ , $C_L = 50\text{ pF}$ , $R_L = 10\text{ k}\Omega$		1.2			
		$V_{DD} = 15\text{ V}$	At $T_A = 25^\circ\text{C}$ , $V_{O(PP)} = V_{DD}/2$ , $C_L = 50\text{ pF}$ , $R_L = 10\text{ k}\Omega$		1.9	2.1		
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ , $V_{O(PP)} =$ $V_{DD}/2$ , $C_L = 50\text{ pF}$ , $R_L = 10\text{ k}\Omega$		1.4			
$\phi_m$	Phase margin	$R_L = 2\text{ k}\Omega$ , $C_L = 100\text{ pF}$			65	$^\circ$		
	Gain margin	$R_L = 2\text{ k}\Omega$ , $C_L = 10\text{ pF}$			18	dB		
$t_s$	Settling time	$V_{DD} = 2.7\text{ V}$ , $V_{(STEP)PP} = 1\text{ V}$ , $A_V = -1$ , $C_L = 10\text{ pF}$ , $R_L = 2\text{ k}\Omega$ , $0.1\%$			2.9	$\mu\text{s}$		
		$V_{DD} = 5\text{ V}$ , $15\text{ V}$ , $V_{(STEP)PP} = 1\text{ V}$ , $A_V = -1$ , $C_L = 47\text{ pF}$ , $R_L = 2\text{ k}\Omega$ , $0.1\%$			2			

## Electrical Characteristics (continued)

at  $T_A = 25^\circ\text{C}$ ,  $V_{DD} = 2.7\text{ V}$ ,  $5\text{ V}$ , and  $15\text{ V}$  (unless otherwise noted).

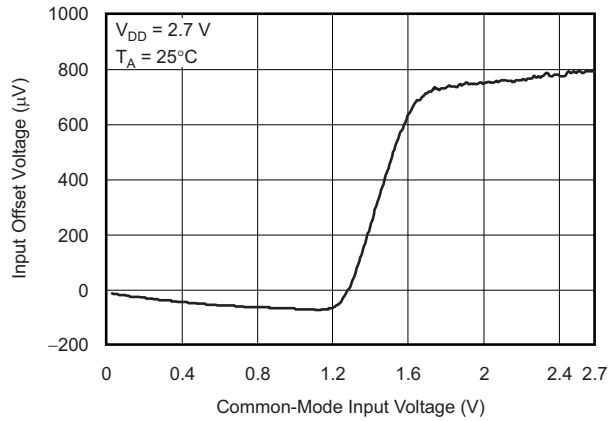
PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
<b>NOISE, DISTORTION PERFORMANCE</b>							
THD + N	Total harmonic distortion plus noise	$V_{DD} = 2.7\text{ V}$	$V_{O(PP)} = V_{DD}/2\text{ V}$ , $R_L = 2\text{ k}\Omega$ , $f = 10\text{ kHz}$ , $A_V = 1$		0.02%		
			$V_{O(PP)} = V_{DD}/2\text{ V}$ , $R_L = 2\text{ k}\Omega$ , $f = 10\text{ kHz}$ , $A_V = 10$		0.05%		
			$V_{O(PP)} = V_{DD}/2\text{ V}$ , $R_L = 2\text{ k}\Omega$ , $f = 10\text{ kHz}$ , $A_V = 100$		0.18%		
		$V_{DD} = 5\text{ V}$ , $15\text{ V}$	$V_{O(PP)} = V_{DD}/2\text{ V}$ , $R_L = 2\text{ k}\Omega$ , $f = 10\text{ kHz}$ , $A_V = 1$		0.02%		
			$V_{O(PP)} = V_{DD}/2\text{ V}$ , $R_L = 2\text{ k}\Omega$ , $f = 10\text{ kHz}$ , $A_V = 10$		0.09%		
			$V_{O(PP)} = V_{DD}/2\text{ V}$ , $R_L = 2\text{ k}\Omega$ , $f = 10\text{ kHz}$ , $A_V = 100$		0.5%		
$V_n$	Equivalent input noise voltage	$f = 1\text{ kHz}$ $f = 10\text{ kHz}$			39		$\text{nV}/\sqrt{\text{Hz}}$
					35		
$I_n$	Equivalent input noise current	$f = 1\text{ kHz}$			0.6		$\text{fA}/\sqrt{\text{Hz}}$
<b>SHUTDOWN CHARACTERISTICS</b>							
$I_{DD(\text{SHDN})}$	Supply current in shutdown mode (TLV2370, TLV2373, TLV2375) (per channel)	$V_{DD} = 2.7\text{ V}$ , $5\text{ V}$ , $\text{SHDN} = 0\text{ V}$	At $T_A = 25^\circ\text{C}$		25	30	$\mu\text{A}$
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$			35	
		$V_{DD} = 15\text{ V}$ , $\text{SHDN} = 0\text{ V}$	At $T_A = 25^\circ\text{C}$		40	45	
			At $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$			50	
$t_{(\text{on})}$	Amplifier turnon time <sup>(1)</sup>	$R_L = 2\text{ k}\Omega$			0.8		$\mu\text{s}$
$t_{(\text{off})}$	Amplifier turnoff time <sup>(1)</sup>	$R_L = 2\text{ k}\Omega$			1		$\mu\text{s}$

(1) Disable time and enable time are defined as the interval between application of the logic signal to the SHDN terminal and the point at which the supply current has reached one half of its final value.

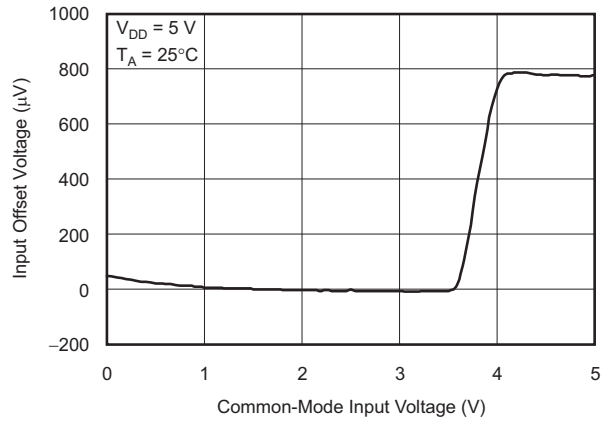
## 7.10 Typical Characteristics

**Table 3. Table of Graphs**

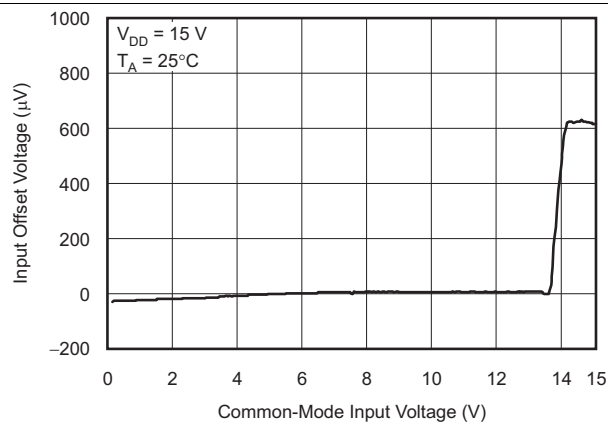
			FIGURE
$V_{IO}$	Input offset voltage	vs Common-mode input voltage	<a href="#">Figure 2</a> , <a href="#">Figure 3</a> , <a href="#">Figure 4</a>
CMRR	Common-mode rejection ratio	vs Frequency	<a href="#">Figure 5</a>
	Input bias and offset current	vs Free-air temperature	<a href="#">Figure 6</a>
$V_{OL}$	Low-level output voltage	vs Low-level output current	<a href="#">Figure 7</a> , <a href="#">Figure 9</a> , <a href="#">Figure 11</a>
$V_{OH}$	High-level output voltage	vs High-level output current	<a href="#">Figure 8</a> , <a href="#">Figure 10</a> , <a href="#">Figure 12</a>
$V_{O(PP)}$	Peak-to-peak output voltage	vs Frequency	<a href="#">Figure 13</a>
$I_{DD}$	Supply current	vs Supply voltage	<a href="#">Figure 14</a>
PSRR	Power supply rejection ratio	vs Frequency	<a href="#">Figure 15</a>
$A_{VD}$	Differential voltage gain and phase	vs Frequency	<a href="#">Figure 16</a>
	Gain-bandwidth product	vs Free-air temperature	<a href="#">Figure 17</a>
SR	Slew rate	vs Supply voltage	<a href="#">Figure 18</a>
		vs Free-air temperature	<a href="#">Figure 19</a>
$\phi_m$	Phase margin	vs Capacitive load	<a href="#">Figure 20</a>
$V_n$	Equivalent input noise voltage	vs Frequency	<a href="#">Figure 21</a>
	Voltage-follower large-signal pulse response		<a href="#">Figure 22</a> , <a href="#">Figure 23</a>
	Voltage-follower small-signal pulse response		<a href="#">Figure 24</a>
	Inverting large-signal response		<a href="#">Figure 25</a> , <a href="#">Figure 26</a>
	Inverting small-signal response		<a href="#">Figure 27</a>
	Crosstalk	vs Frequency	<a href="#">Figure 28</a>
	Shutdown forward & reverse isolation	vs Frequency	<a href="#">Figure 29</a>
$I_{DD(SHDN)}$	Shutdown supply current	vs Supply voltage	<a href="#">Figure 30</a>
$I_{DD(SHDN)}$	Shutdown pin leakage current	vs Shutdown pin voltage	<a href="#">Figure 31</a>
$I_{DD(SHDN)}$	Shutdown supply current, output voltage	vs Time	<a href="#">Figure 32</a> , <a href="#">Figure 33</a>



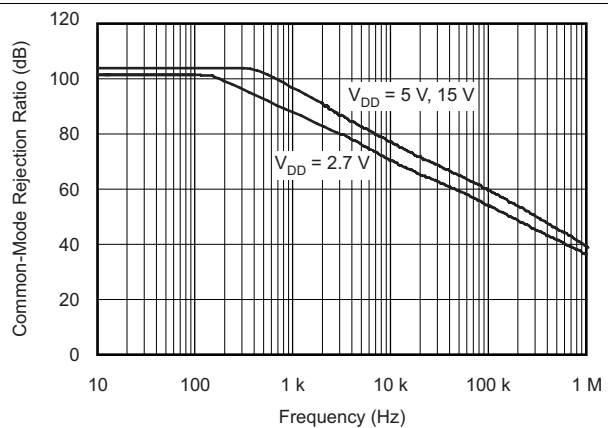
**Figure 2. Input Offset Voltage vs Common-Mode Input Voltage**



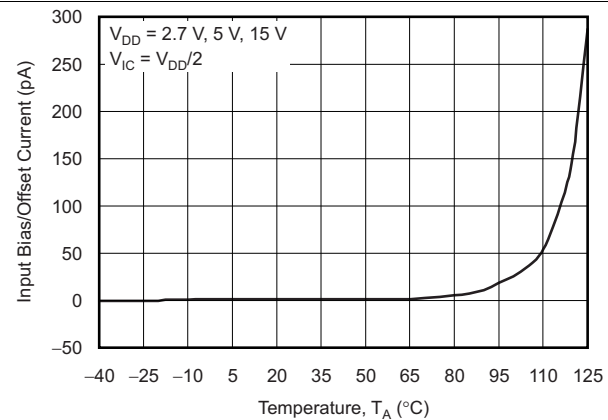
**Figure 3. Input Offset Voltage vs Common-Mode Input Voltage**



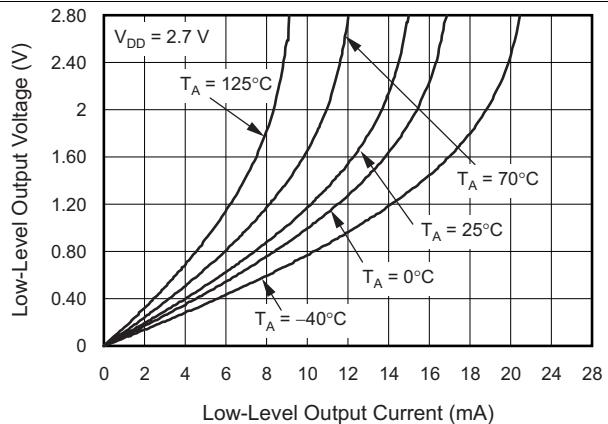
**Figure 4. Input Offset Voltage vs Common-Mode Input Voltage**



**Figure 5. Common-Mode Rejection Ratio vs Frequency**



**Figure 6. Input Bias or Offset Current vs Free-Air Temperature**



**Figure 7. Low-Level Output Voltage vs Low-Level Output Current**





Figure 8. High-Level Output Voltage vs High-Level Output Current

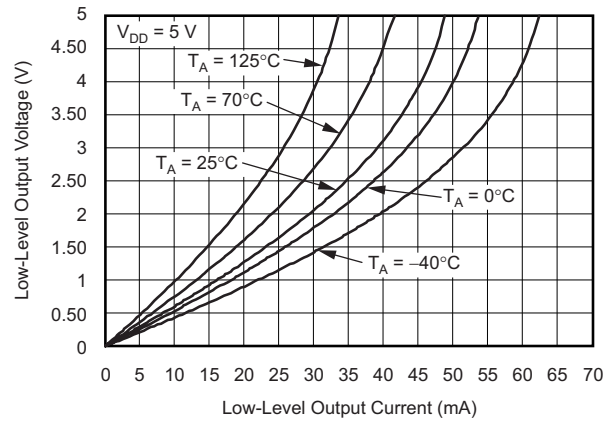


Figure 9. Low-Level Output Voltage vs Low-Level Output Current



Figure 10. High-Level Output Voltage vs High-Level Output Current

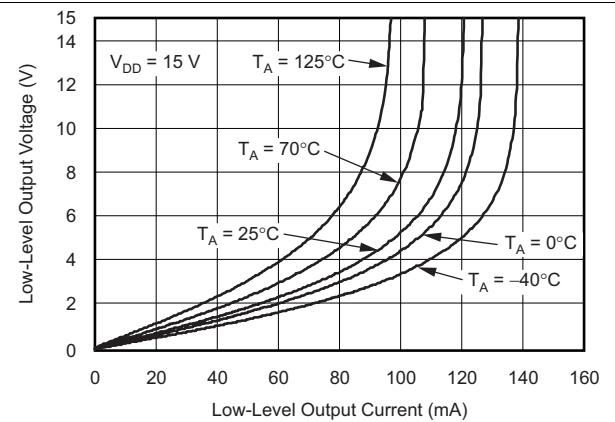


Figure 11. Low-Level Output Voltage vs Low-Level Output Current



Figure 12. High-Level Output Voltage vs High-Level Output Current

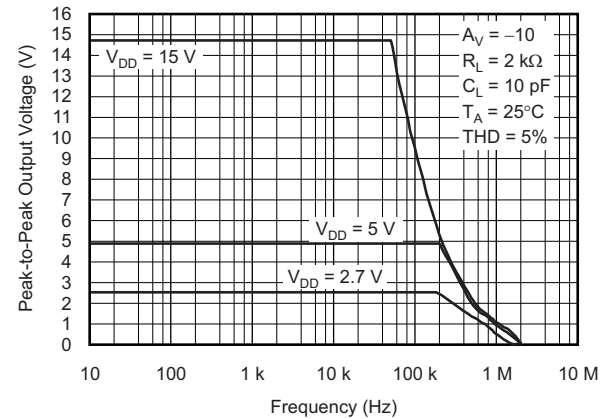


Figure 13. Peak-to-Peak Output Voltage vs Frequency

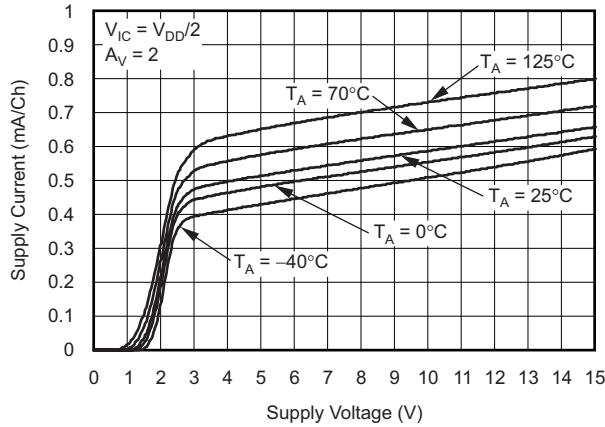


Figure 14. Supply Current vs Supply Voltage

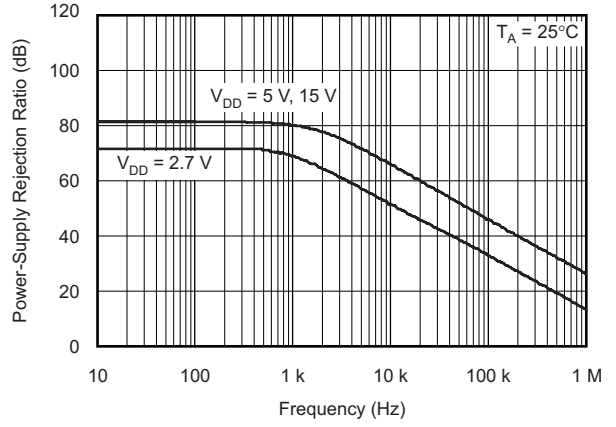


Figure 15. Power Supply Rejection Ratio vs Frequency

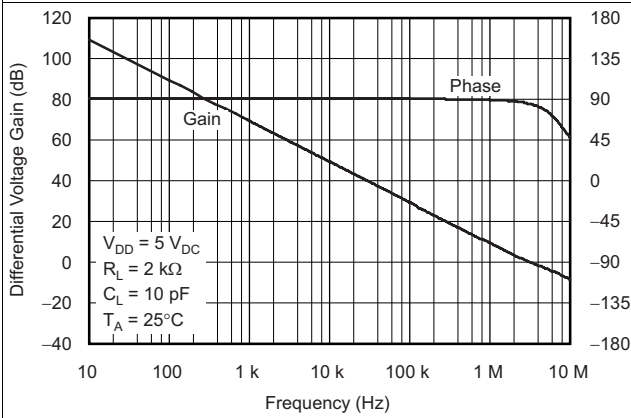


Figure 16. Differential Voltage Gain and Phase vs Frequency

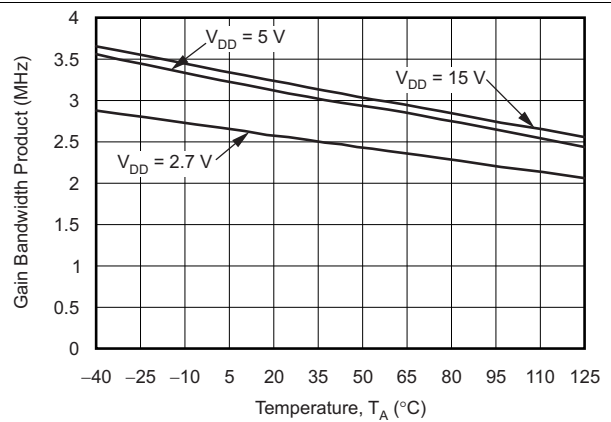


Figure 17. Gain Bandwidth Product vs Free-Air Temperature

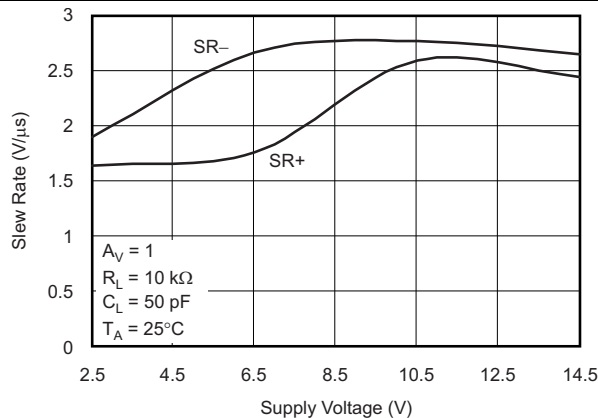


Figure 18. Slew Rate vs Supply Voltage

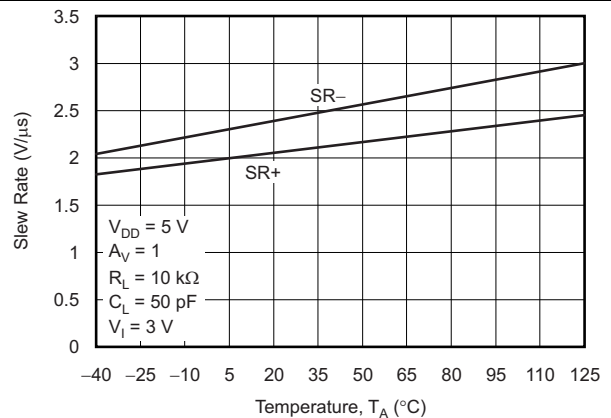


Figure 19. Slew Rate vs Free-Air Temperature

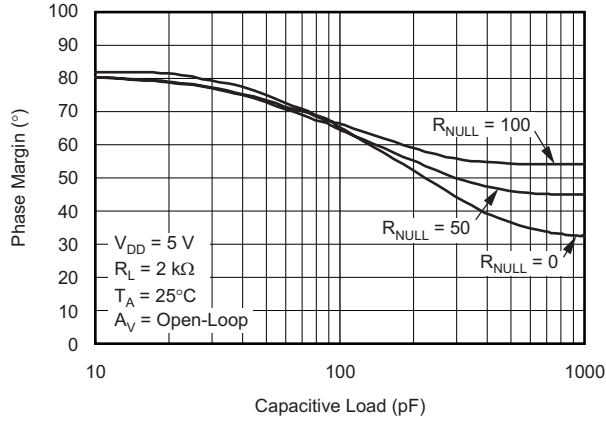


Figure 20. Phase Margin vs Capacitive Load

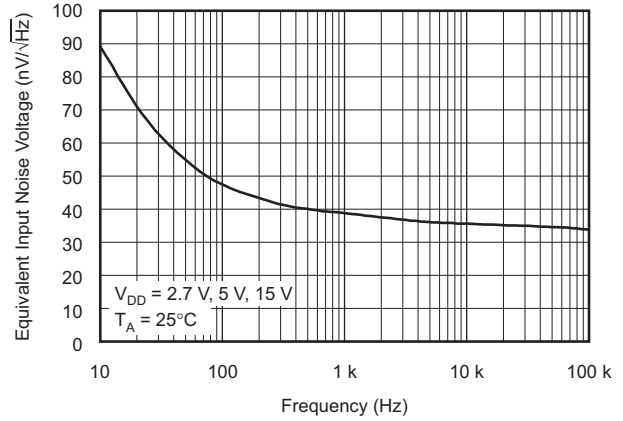


Figure 21. Equivalent Input Noise Voltage vs Frequency

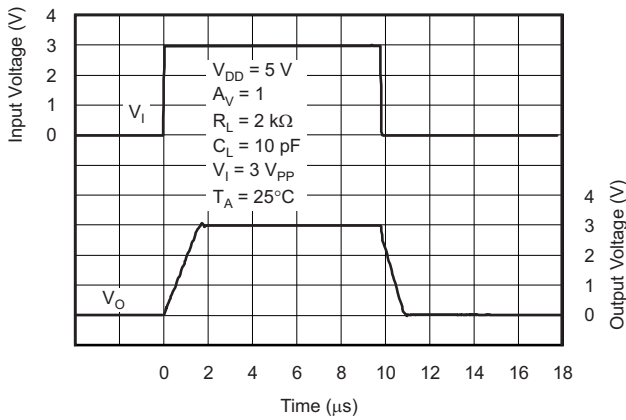


Figure 22. Voltage-Follower Large-Signal Pulse Response

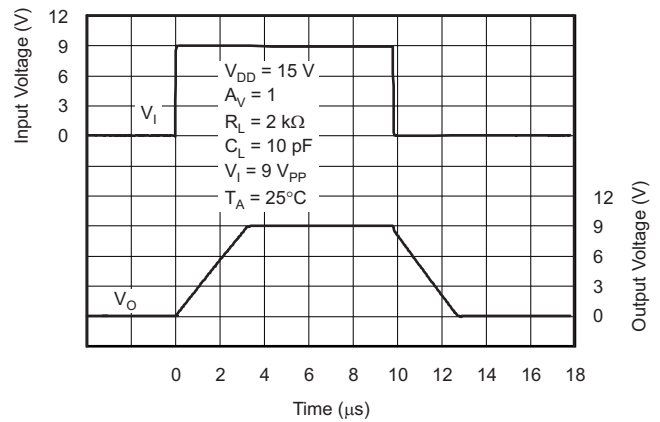


Figure 23. Voltage-Follower Large-Signal Pulse Response

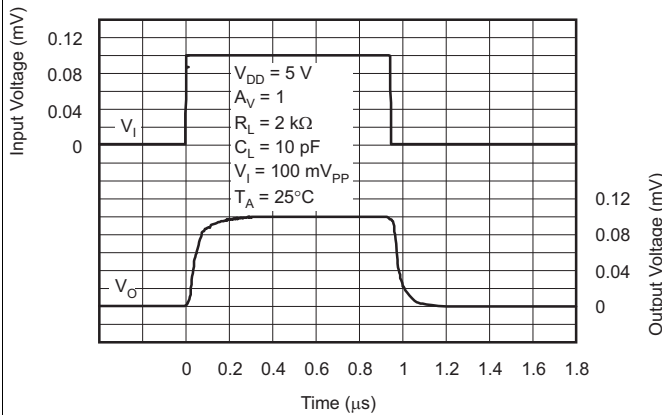


Figure 24. Voltage-Follower Small-Signal Pulse Response

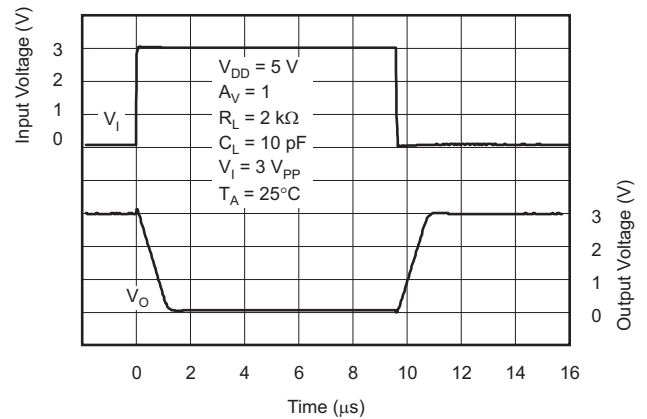
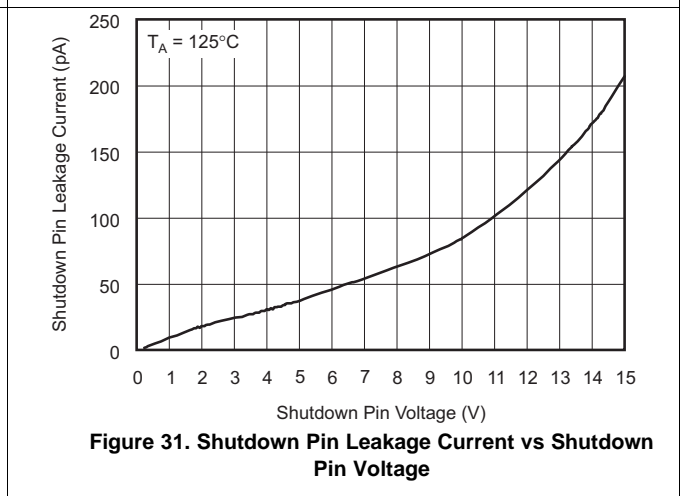
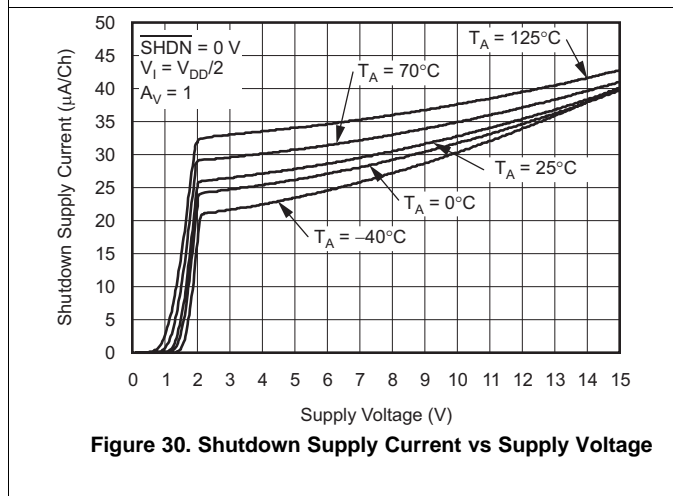
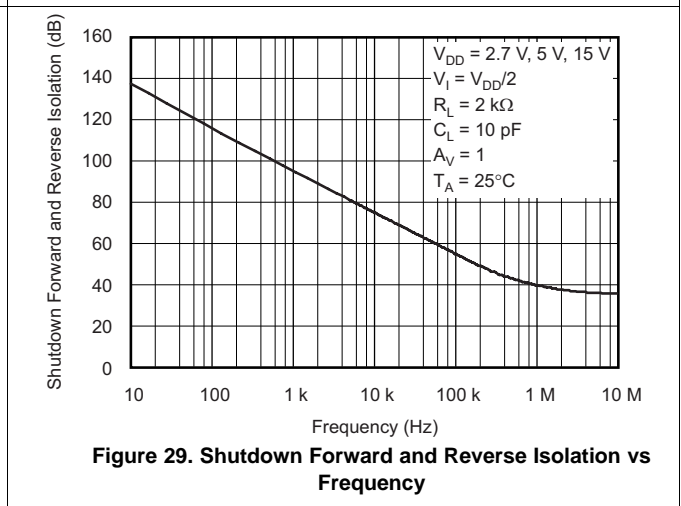
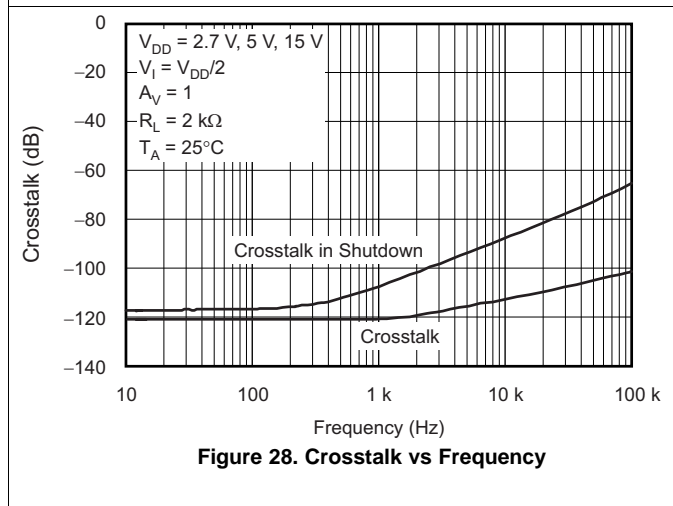
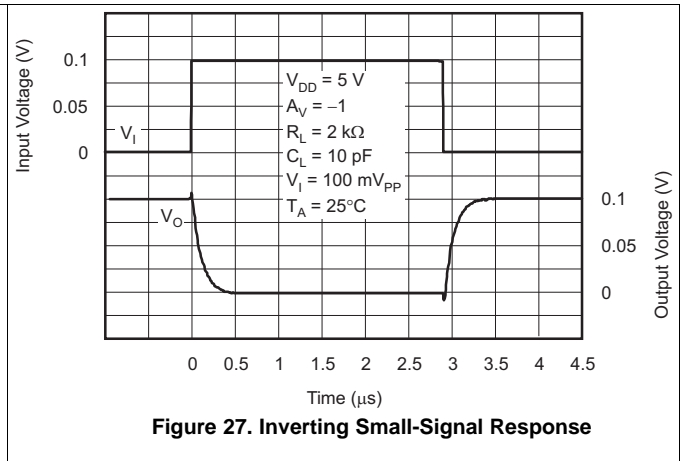
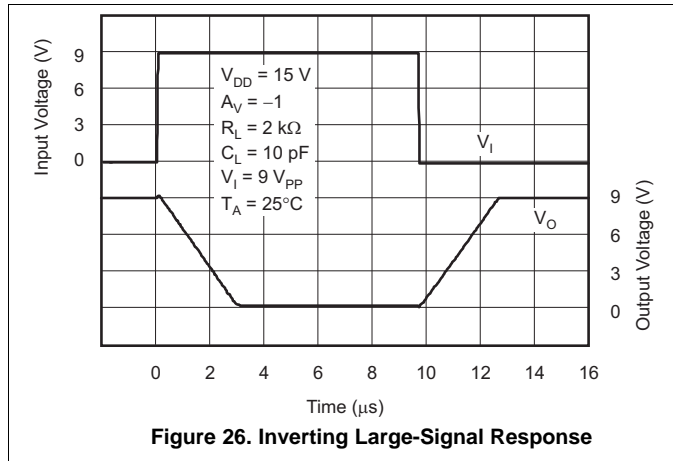


Figure 25. Inverting Large-Signal Response



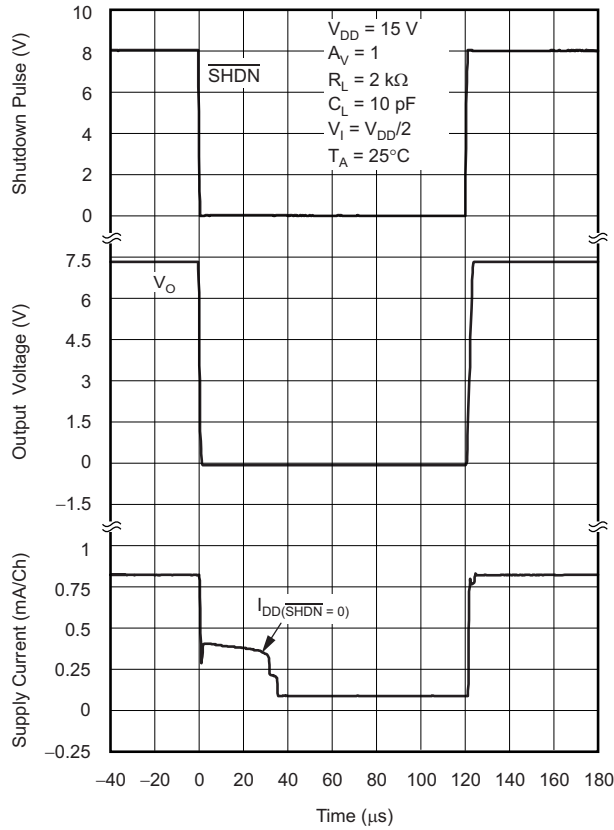


Figure 32. Shutdown Supply Current and Output Voltage vs Time

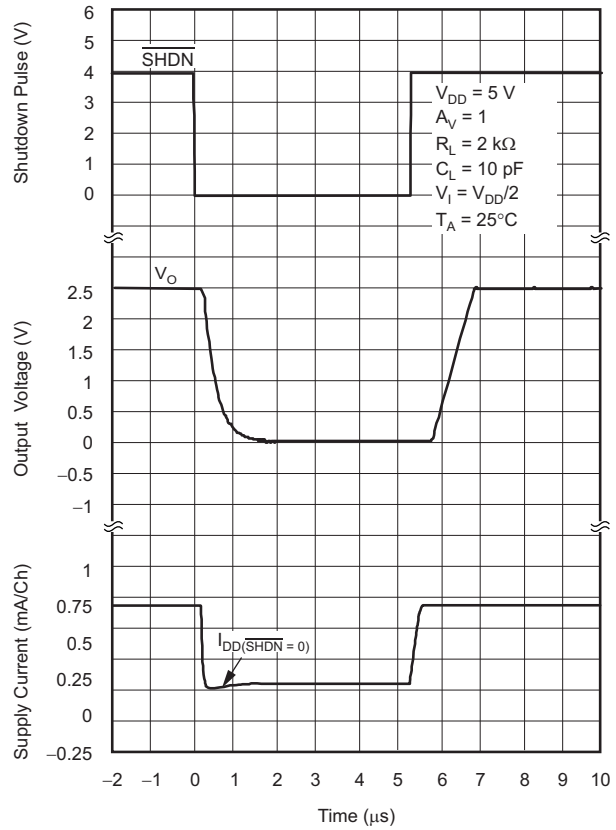


Figure 33. Shutdown Supply Current/output Voltage vs Time

## 8 Detailed Description

### 8.1 Overview

The TLV237x single-supply CMOS operational amplifiers provide rail-to-rail input and output capability with 3-MHz bandwidth. Consuming only 550  $\mu\text{A}$  the TLV237x is the perfect choice for portable and battery-operated applications. The maximum recommended supply voltage is 16 V, which allows the devices to be operated from ( $\pm 8\text{-V}$  supplies down to  $\pm 1.35\text{ V}$ ) a variety of rechargeable cells. The rail-to-rail inputs with high input impedance make the TLV237x ideal for sensor signal-conditioning applications.

### 8.2 Functional Block Diagram



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### 8.3 Feature Description

#### 8.3.1 Rail-to-Rail Input Operation

The TLV237x input stage consists of two differential transistor pairs, NMOS and PMOS, that operate together to achieve rail-to-rail input operation. The transition point between these two pairs can be seen in [Figure 2](#), [Figure 3](#), and [Figure 4](#) for a 2.7-V, 5-V, and 15-V supply. As the common-mode input voltage approaches the positive supply rail, the input pair switches from the PMOS differential pair to the NMOS differential pair. This transition occurs approximately 1.35 V from the positive rail and results in a change in offset voltage due to different device characteristics between the NMOS and PMOS pairs. If the input signal to the device is large enough to swing between both rails, this transition results in a reduction in common-mode rejection ratio (CMRR). If the input signal does not swing between both rails, it is best to bias the signal in the region where only one input pair is active. This is the region in [Figure 2](#) through [Figure 4](#) where the offset voltage varies slightly across the input range and optimal CMRR can be achieved. This has the greatest impact when operating from a 2.7-V supply voltage.

#### 8.3.2 Driving a Capacitive Load

When the amplifier is configured in this manner, capacitive loading directly on the output decreases the device phase margin leading to high frequency ringing or oscillations. Therefore, for capacitive loads of greater than 10 pF, TI recommends that a resistor be placed in series (RNULL) with the output of the amplifier, as shown in [Figure 34](#). A minimum value of 20  $\Omega$  should work well for most applications.

## Feature Description (continued)

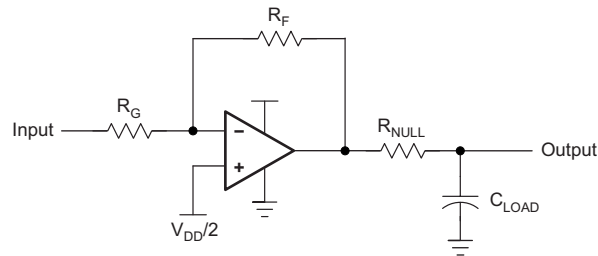


Figure 34. Driving a Capacitive Load

### 8.3.3 Offset Voltage

The output offset voltage, ( $V_{OO}$ ) is the sum of the input offset voltage ( $V_{IO}$ ) and both input bias currents ( $I_{IB}$ ) times the corresponding gains. Figure 35 can be used to calculate the output offset voltage:

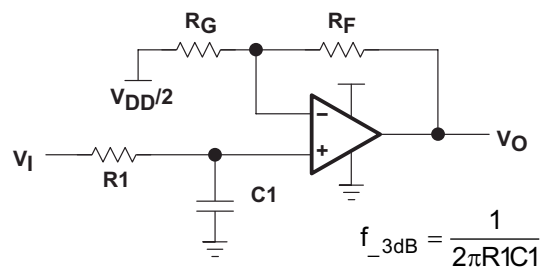


$$V_{OO} = V_{IO} \left[ 1 + \left( \frac{R_F}{R_G} \right) \right] \pm I_{IB+} R_S \left[ 1 + \left( \frac{R_F}{R_G} \right) \right] \pm I_{IB-} R_F$$

Figure 35. Output Offset Voltage Model

### 8.3.4 General Configurations

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to accomplish this is to place an RC filter at the noninverting terminal of the amplifier (see Figure 36).



$$\frac{V_O}{V_I} = \left( 1 + \frac{R_F}{R_G} \right) \left( \frac{1}{1 + 2\pi f R_1 C_1} \right)$$

Figure 36. Single-Pole Low-Pass Filter

If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task. For best results, the amplifier must have a bandwidth that is 8 to 10 times the filter frequency bandwidth. Failure to do this can result in phase shift of the amplifier.

## Feature Description (continued)

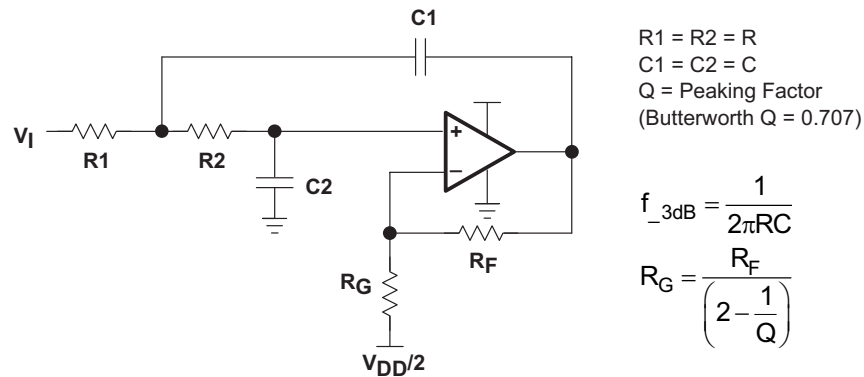


Figure 37. 2-Pole Low-Pass Sallen-Key Filter

### 8.3.5 Shutdown Function

Three members of the TLV237x family (TLV2370, TLV2373, and TLV2375) have a shutdown terminal for conserving battery life in portable applications. When the shutdown terminal is tied low, the supply current is reduced to 25  $\mu\text{A}/\text{channel}$ , the amplifier is disabled, and the outputs are placed in a high impedance mode. To enable the amplifier, the shutdown terminal can either be left floating or pulled high. When the shutdown terminal is left floating, take care to ensure that parasitic leakage current at the shutdown terminal does not inadvertently place the operational amplifier into shutdown.

### 8.4 Device Functional Modes

The TLV2371, TLV2372, and TLV2374 have a single functional mode. These devices are operational as long as the power-supply voltage is between 2.7 V ( $\pm 1.35$  V) and 16 V ( $\pm 8$  V).

The TLV2370, TLV2373, and TLV2375 are likewise operational as long as the power-supply voltage is between 2.7 V ( $\pm 1.35$  V) and 16 V ( $\pm 8$  V), additionally these devices also have a shutdown capability. When the shutdown control pin is driven below 0.8 V above ground, the device is in shutdown. If the shutdown control pin voltage is driven to greater than 2 V above ground, the device is in its normal operating mode. See [Shutdown Function](#) for additional information regarding shutdown operation.



## 9 Application and Implementation

### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 9.1 Application Information

When designing for low power, choose system components carefully. To minimize current consumption, select large-value resistors. Any resistors can react with stray capacitance in the circuit and the input capacitance of the operational amplifier. These parasitic RC combinations can affect the stability of the overall system. Use of a feedback capacitor assures stability and limits overshoot or gain peaking.

### 9.2 Typical Application

A typical application for an operational amplifier is an inverting amplifier, as shown in [Figure 38](#). An inverting amplifier takes a positive voltage on the input and outputs a signal inverted to the input, making a negative voltage of the same magnitude. In the same manner, the amplifier also makes negative input voltages positive on the output. In addition, amplification can be added by selecting the input resistor  $R_I$  and the feedback resistor  $R_F$ .



**Figure 38. Application Schematic**

#### 9.2.1 Design Requirements

The supply voltage must be chosen to be larger than the input voltage range and the desired output range. The limits of the input common-mode range ( $V_{CM}$ ) and the output voltage swing to the rails ( $V_O$ ) must also be considered. For instance, this application scales a signal of  $\pm 0.5$  V (1 V) to  $\pm 1.8$  V (3.6 V). Setting the supply at  $\pm 2.5$  V is sufficient to accommodate this application.

#### 9.2.2 Detailed Design Procedure

Determine the gain required by the inverting amplifier using [Equation 1](#) and [Equation 2](#):

$$A_V = \frac{V_{OUT}}{V_{IN}} \tag{1}$$

$$A_V = \frac{1.8}{-0.5} = -3.6 \tag{2}$$

When the desired gain is determined, choose a value for  $R_I$  or  $R_F$ . Choosing a value in the  $k\Omega$  range is desirable for general-purpose applications because the amplifier circuit uses currents in the milliamp range. This milliamp current range ensures the device does not draw too much current. The trade-off is that very large resistors (100s of  $k\Omega$ ) draw the smallest current but generate the highest noise. Very small resistors (100s of  $\Omega$ ) generate low noise but draw high current. This example uses 10  $k\Omega$  for  $R_I$ , meaning 36  $k\Omega$  is used for  $R_F$ . These values are determined by [Equation 3](#):

### Typical Application (continued)

$$A_V = -\frac{R_F}{R_I} \quad (3)$$

#### 9.2.3 Application Curve

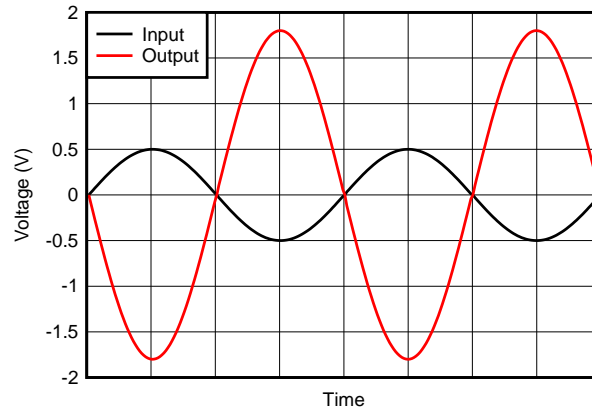


Figure 39. Inverting Amplifier Input and Output

## 10 Power Supply Recommendations

The TLV237x family is specified for operation from 2.7 V to 15 V ( $\pm 1.35$  V to  $\pm 7.5$  V); many specifications apply from  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ . The *Typical Characteristics* presents parameters that can exhibit significant variance with regard to operating voltage or temperature.

### CAUTION

Supply voltages larger than 16 V can permanently damage the device (see the *Absolute Maximum Ratings* table).

Place 0.1- $\mu\text{F}$  bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement; see *Layout*.

## 11 Layout

### 11.1 Layout Guidelines

To achieve the levels of high performance of the TLV237x, follow proper printed-circuit board design techniques. A general set of guidelines is given in the following.

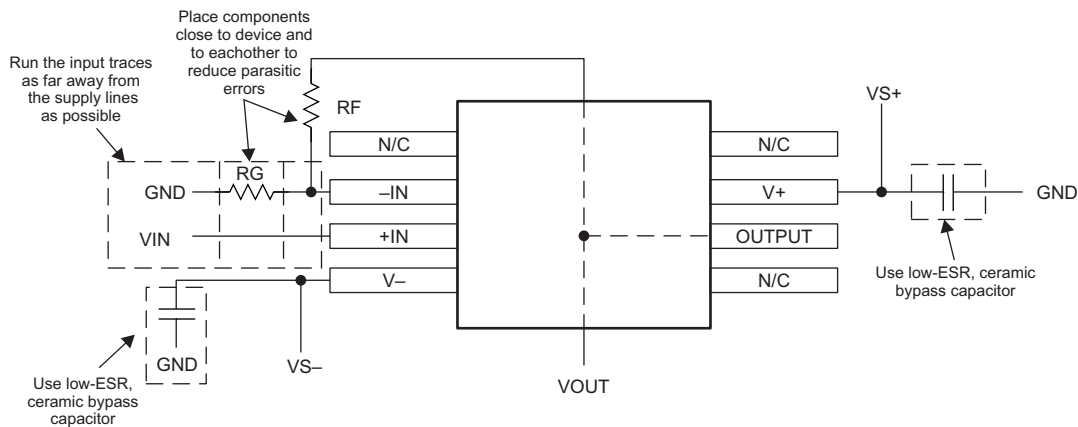
- Ground planes—TI highly recommends using a ground plane on the board to provide all components with a low inductive ground connection. However, in the areas of the amplifier inputs and output, the ground plane can be removed to minimize the stray capacitance.
- Proper power supply decoupling—Use a 6.8- $\mu\text{F}$  tantalum capacitor in parallel with a 0.1- $\mu\text{F}$  ceramic capacitor on each supply terminal. It may be possible to share the tantalum among several amplifiers depending on the application, but a 0.1- $\mu\text{F}$  ceramic capacitor should always be used on the supply terminal of every amplifier. In addition, the 0.1- $\mu\text{F}$  capacitor must be placed as close as possible to the supply terminal. As this distance increases, the inductance in the connecting trace makes the capacitor less effective. The designer should strive for distances of less than 0.1 inches between the device power terminals and the ceramic capacitors.
- Sockets—Sockets can be used but are not recommended. The additional lead inductance in the socket pins will often lead to stability problems. Surface-mount packages soldered directly to the printed-circuit board is the best implementation.
- Short trace runs and compact part placements—Optimum high performance is achieved when stray series inductance has been minimized. To realize this, the circuit layout must be made as compact as possible, thereby minimizing the length of all trace runs. Pay particular attention to the inverting input of the amplifier. Its length must be kept as short as possible. This helps to minimize stray capacitance at the input of the amplifier.
- Surface-mount passive components—Using surface-mount passive components is recommended for high performance amplifier circuits for several reasons. First, because of the extremely low lead inductance of surface-mount components, the problem with stray series inductance is greatly reduced. Second, the small size of surface-mount components naturally leads to a more compact layout thereby minimizing both stray inductance and capacitance. If leaded components are used, TI recommends that the lead lengths be kept as short as possible.

### 11.2 Layout Example



Figure 40. Schematic Representation

## Layout Example (continued)



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**Figure 41. Operational Amplifier Board Layout for Noninverting Configuration**

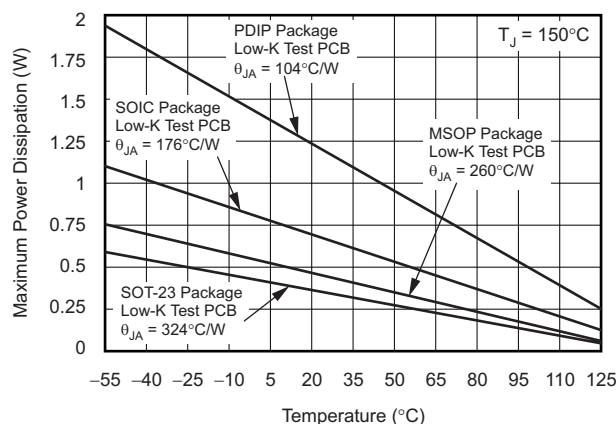
## 11.3 Power Dissipation Considerations

For a given  $\theta_{JA}$ , the maximum power dissipation is shown in [Figure 42](#) and is calculated by [Equation 4](#):

$$P_D = \left( \frac{T_{MAX} - T_A}{\theta_{JA}} \right)$$

where

- $P_D$  = Maximum power dissipation of TLV237x IC (watts)
  - $T_{MAX}$  = Absolute maximum junction temperature (150°C)
  - $T_A$  = Free-ambient air temperature (°C)
  - $\theta_{JA} = \theta_{JC}$  (Thermal coefficient from junction to case) +  $\theta_{CA}$  (Thermal coefficient from case to ambient air (°C/W))
- (4)



Results are with no air flow and using JEDEC Standard Low-K test PCB.

**Figure 42. Maximum Power Dissipation vs Free-Air Temperature**

## 12 Device and Documentation Support

### 12.1 Documentation Support

#### 12.1.1 Related Documentation

For related documentation see the following:

[EVM Selection Guide](#) (SLOU060)

### 12.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

**Table 4. Related Links**

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
TLV2370	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>
TLV2371	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>
TLV2372	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>
TLV2373	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>
TLV2374	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>
TLV2375	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>

### 12.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 12.4 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At [e2e.ti.com](http://e2e.ti.com), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

### 12.5 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

### 12.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 12.7 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLV2370ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2370I	<a href="#">Samples</a>
TLV2370IDBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBFI	<a href="#">Samples</a>
TLV2370IDBVRG4	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBFI	<a href="#">Samples</a>
TLV2370IDBVT	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBFI	<a href="#">Samples</a>
TLV2370IDBVTG4	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBFI	<a href="#">Samples</a>
TLV2370IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2370I	<a href="#">Samples</a>
TLV2370IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2370I	<a href="#">Samples</a>
TLV2370IP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	2370I	<a href="#">Samples</a>
TLV2370IPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	2370I	<a href="#">Samples</a>
TLV2371ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2371I	<a href="#">Samples</a>
TLV2371IDBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBGI	<a href="#">Samples</a>
TLV2371IDBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBGI	<a href="#">Samples</a>
TLV2371IDBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBGI	<a href="#">Samples</a>
TLV2371IDBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBGI	<a href="#">Samples</a>
TLV2371IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2371I	<a href="#">Samples</a>
TLV2371IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2371I	<a href="#">Samples</a>
TLV2371IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2371I	<a href="#">Samples</a>

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLV2371IP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	2371I	<a href="#">Samples</a>
TLV2371IPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	2371I	<a href="#">Samples</a>
TLV2372ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2372I	<a href="#">Samples</a>
TLV2372IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2372I	<a href="#">Samples</a>
TLV2372IDGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	APG	<a href="#">Samples</a>
TLV2372IDGKG4	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	APG	<a href="#">Samples</a>
TLV2372IDGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	APG	<a href="#">Samples</a>
TLV2372IDGKRG4	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	APG	<a href="#">Samples</a>
TLV2372IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2372I	<a href="#">Samples</a>
TLV2372IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2372I	<a href="#">Samples</a>
TLV2372IP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	2372I	<a href="#">Samples</a>
TLV2372IPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	2372I	<a href="#">Samples</a>
TLV2373ID	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2373I	<a href="#">Samples</a>
TLV2373IDG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2373I	<a href="#">Samples</a>
TLV2373IDGS	ACTIVE	VSSOP	DGS	10	80	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	API	<a href="#">Samples</a>
TLV2373IDGSG4	ACTIVE	VSSOP	DGS	10	80	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	API	<a href="#">Samples</a>
TLV2373IDGSR	ACTIVE	VSSOP	DGS	10	2500	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	API	<a href="#">Samples</a>
TLV2373IDGSRG4	ACTIVE	VSSOP	DGS	10	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	API	<a href="#">Samples</a>



Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLV2373IDR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2373I	<a href="#">Samples</a>
TLV2373IDRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2373I	<a href="#">Samples</a>
TLV2373IN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2373I	<a href="#">Samples</a>
TLV2374ID	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2374I	<a href="#">Samples</a>
TLV2374IDG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2374I	<a href="#">Samples</a>
TLV2374IDR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2374I	<a href="#">Samples</a>
TLV2374IDRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2374I	<a href="#">Samples</a>
TLV2374IN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	2374I	<a href="#">Samples</a>
TLV2374INE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	2374I	<a href="#">Samples</a>
TLV2374IPW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2374I	<a href="#">Samples</a>
TLV2374IPWG4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2374I	<a href="#">Samples</a>
TLV2374IPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2374I	<a href="#">Samples</a>
TLV2374IPWRG4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2374I	<a href="#">Samples</a>
TLV2375ID	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2375I	<a href="#">Samples</a>
TLV2375IDG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2375I	<a href="#">Samples</a>
TLV2375IDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2375I	<a href="#">Samples</a>
TLV2375IDRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2375I	<a href="#">Samples</a>
TLV2375IN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	2375I	<a href="#">Samples</a>

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLV2375IPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2375I	<a href="#">Samples</a>
TLV2375IPWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2375I	<a href="#">Samples</a>
TLV2375IPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2375I	<a href="#">Samples</a>
TLV2375IPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2375I	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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**OTHER QUALIFIED VERSIONS OF TLV2371, TLV2372, TLV2374 :**

- Automotive: [TLV2371-Q1](#), [TLV2372-Q1](#), [TLV2374-Q1](#)
- Enhanced Product: [TLV2371-EP](#), [TLV2374-EP](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

## TAPE AND REEL INFORMATION



### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2370IDBVR	SOT-23	DBV	6	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2370IDBVT	SOT-23	DBV	6	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2370IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2371IDBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TLV2371IDBVT	SOT-23	DBV	5	250	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
TLV2371IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2372IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2372IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2372IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2373IDGSR	VSSOP	DGS	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2373IDGSR	VSSOP	DGS	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2373IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2374IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2374IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2375IDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TLV2375IPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2370IDBVR	SOT-23	DBV	6	3000	182.0	182.0	20.0
TLV2370IDBVT	SOT-23	DBV	6	250	182.0	182.0	20.0
TLV2370IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2371IDBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TLV2371IDBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TLV2371IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2372IDGKR	VSSOP	DGK	8	2500	358.0	335.0	35.0
TLV2372IDGKR	VSSOP	DGK	8	2500	364.0	364.0	27.0
TLV2372IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2373IDGSR	VSSOP	DGS	10	2500	358.0	335.0	35.0
TLV2373IDGSR	VSSOP	DGS	10	2500	364.0	364.0	27.0
TLV2373IDR	SOIC	D	14	2500	333.2	345.9	28.6
TLV2374IDR	SOIC	D	14	2500	333.2	345.9	28.6
TLV2374IPWR	TSSOP	PW	14	2000	367.0	367.0	35.0
TLV2375IDR	SOIC	D	16	2500	333.2	345.9	28.6
TLV2375IPWR	TSSOP	PW	16	2000	367.0	367.0	35.0

# MECHANICAL DATA

DBV (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- Falls within JEDEC MO-178 Variation AB, except minimum lead width.

DBV (R-PDSO-G6)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
  - D. Publication IPC-7351 is recommended for alternate designs.
  - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



4040047-6/M 06/11

- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  -  C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
  -  D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
  - E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Publication IPC-7351 is recommended for alternate designs.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  -  Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
  -  Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
  - E. Reference JEDEC MS-012 variation AB.

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



4040064-3/G 02/11

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  -  C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
  -  D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
  - E. Falls within JEDEC MO-153

PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



4040064-4/G 02/11

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  -  Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
  -  Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
  - E. Falls within JEDEC MO-153

PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Publication IPC-7351 is recommended for alternate designs.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
  - Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
  - E. Reference JEDEC MS-012 variation AA.

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Publication IPC-7351 is recommended for alternate designs.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Falls within JEDEC MS-001 variation BA.

N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
  - The 20 pin end lead shoulder width is a vendor option, either half or full width.

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Falls within JEDEC MO-178 Variation AA.

DBV (R-PDSO-G5)

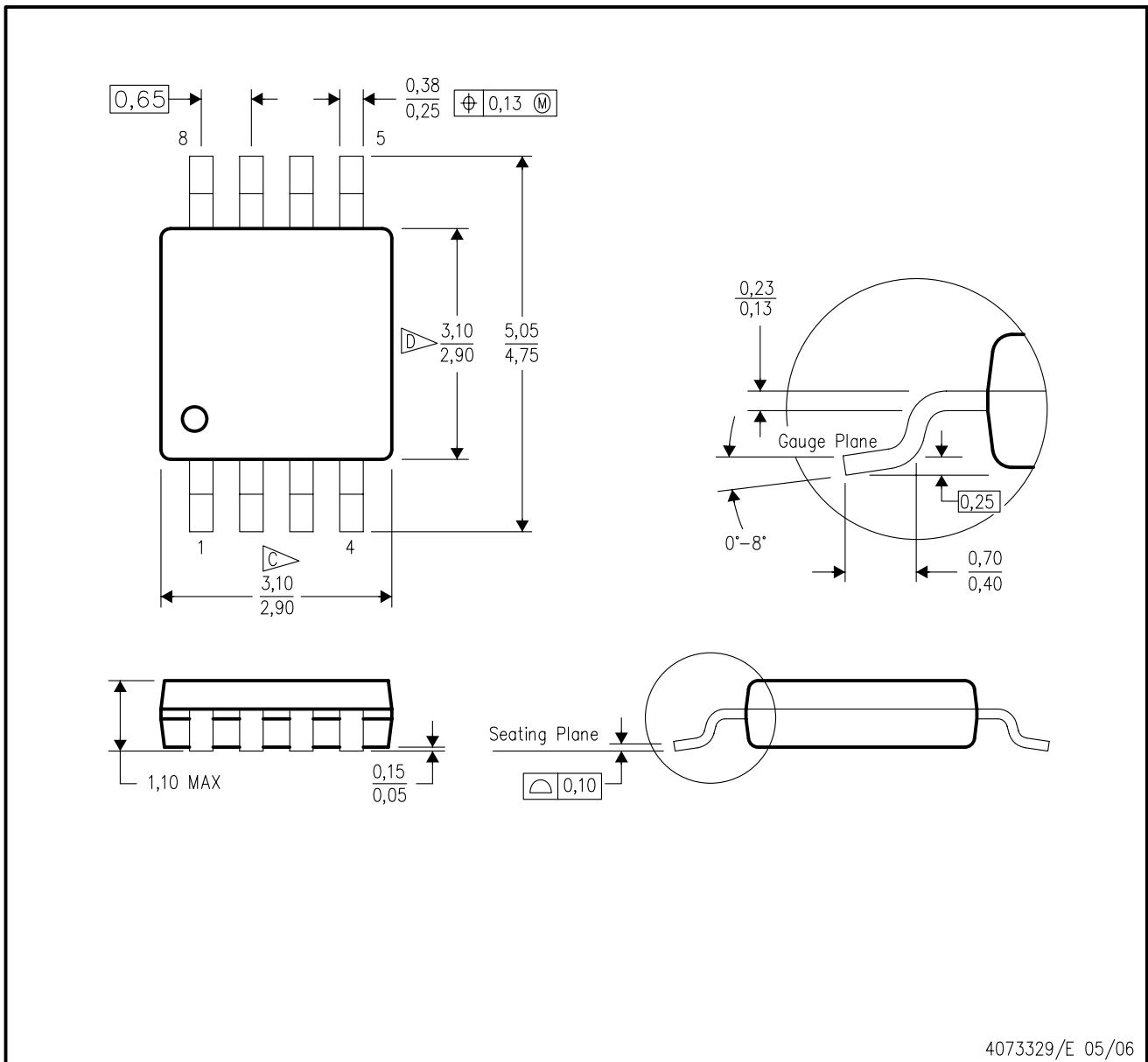
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
  - D. Publication IPC-7351 is recommended for alternate designs.
  - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



4073329/E 05/06

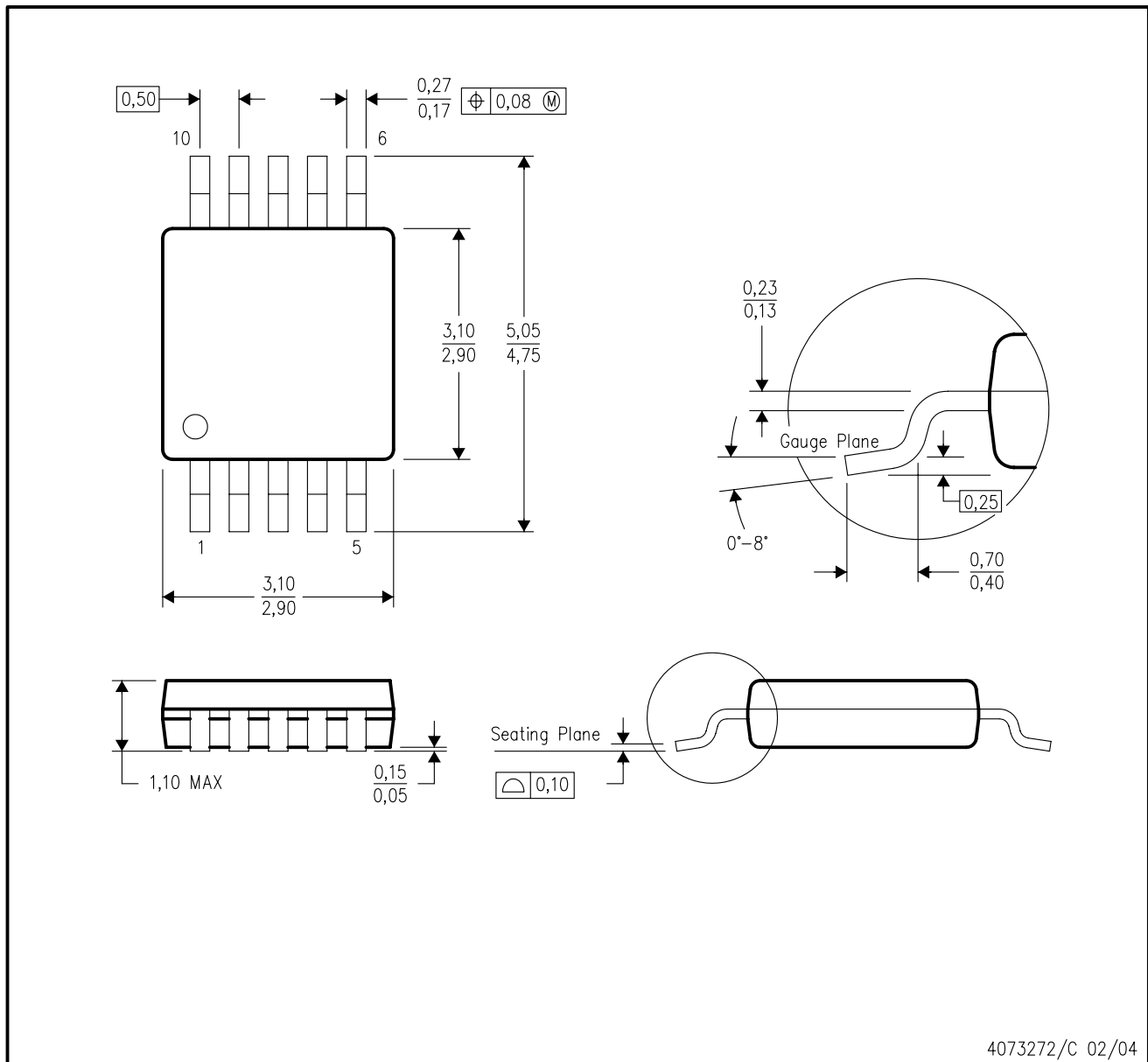
- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
  - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
  - E. Falls within JEDEC MO-187 variation AA, except interlead flash.



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

DGS (S-PDSO-G10)

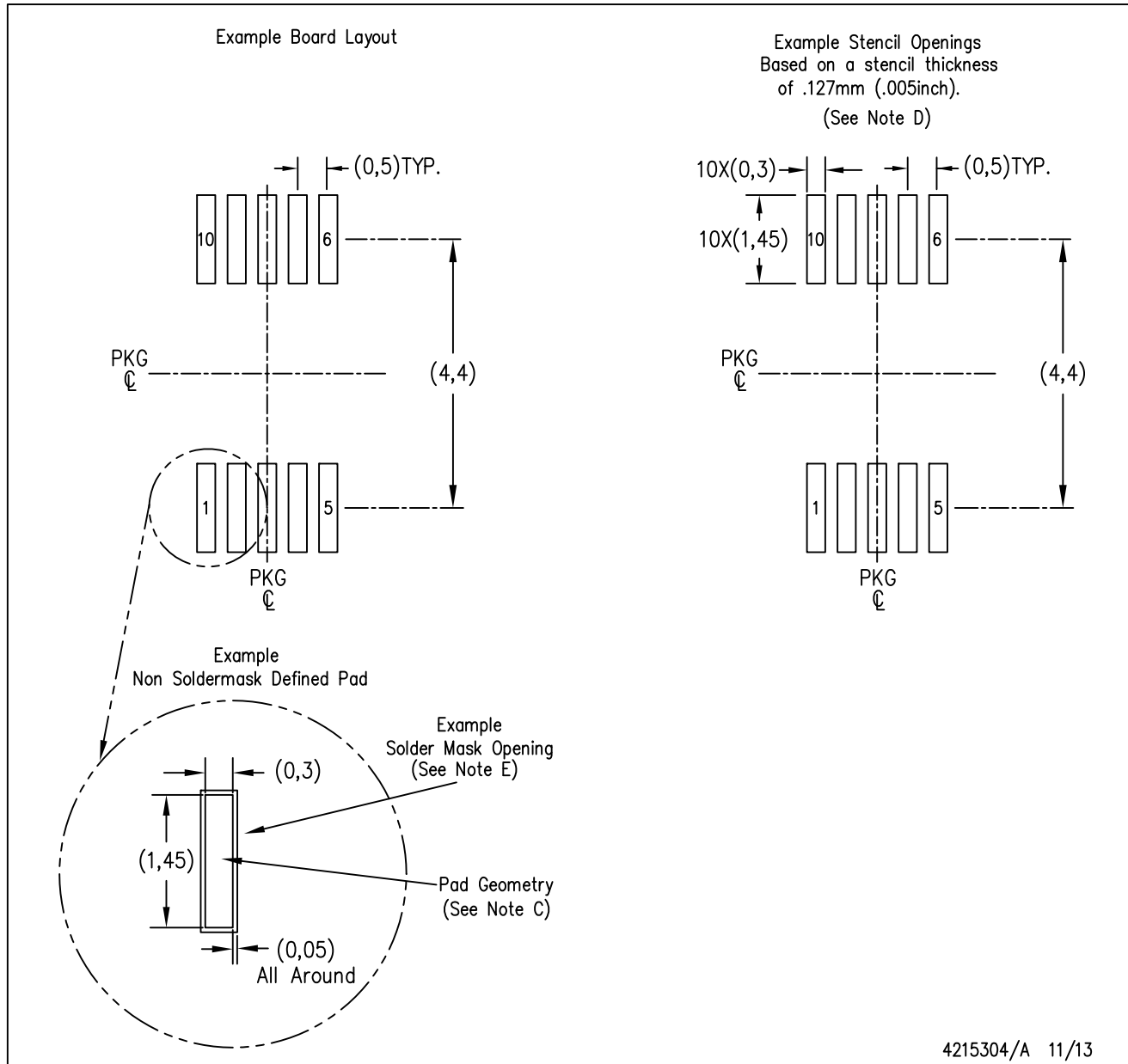
PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion.
  - D. Falls within JEDEC MO-187 variation BA.

DGS (S-PDSO-G10)

PLASTIC SMALL OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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